

IRP1608N06-B50

SMD Type 940nm Infrared Emitter

Features

- Small double-end package
- Viewing Angle = $\pm 75^{\circ}$
- High reliability
- Good spectral matching to Si photo detector
- RoHS compliance

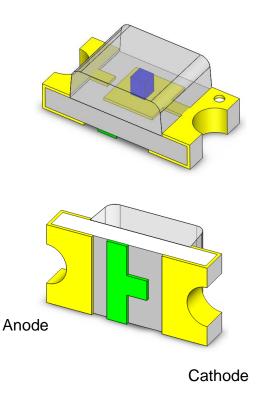
Applications

Infrared sensor

Description

The IRP1608N06-B50 is a GaAlAs infrared LED housed in a miniature SMD package. The device has a peak wavelength of 940nm LED spectrally matched with phototransistor or photodiode.

Package Outline



Schematic





Absolute Maximum Rating at 25°C

Symbol	Parameters	Ratings	Units	Notes
lF	Continuous Forward Current	70	mA	
IFP	Peak Forward Current	0.7	А	1
V _R	Reverse Voltage	5	V	
T _{opr}	Operating Temperature	-40 ~ +85	0C	
T _{stg}	Storage Temperature	-40 ~ +100	0C	
T _{sol}	Soldering Temperature	260	٥C	2
PD	Power Dissipation at(or below) 25°CFree Air Temperature	119	mW	

Electro-Optical Characteristics TA = 25°C (unless otherwise specified)

Optical Characteristics

Symbol	Parameters	Test Conditions	Min	Тур	Max	Units	Notes
le	Radiant Intensity	I _F =20mA	0.4	0.8	1.3	mW/sr	3
		I _F =70mA	-	2.5	-		
λр	Peak Wavelength	I _F =20mA	-	940	-	nm	
Δλ	Spectral Bandwidth	I _F =20mA	-	50	-	nm	
θ1/2	Angle of Half Intensity	I _F =20mA	-	±75	-	deg	

Electrical Characteristics

Symbol	Parameters	Test Conditions	Min	Тур	Max	Units	Notes
VF	Forward Voltage	I _F =20mA	1.0	1.2	1.5	V	
		I _F =70mA	1.1	1.34	1.7		
I _R	Reverse Current	V _R =5V	-	-	10	μA	

Notes:

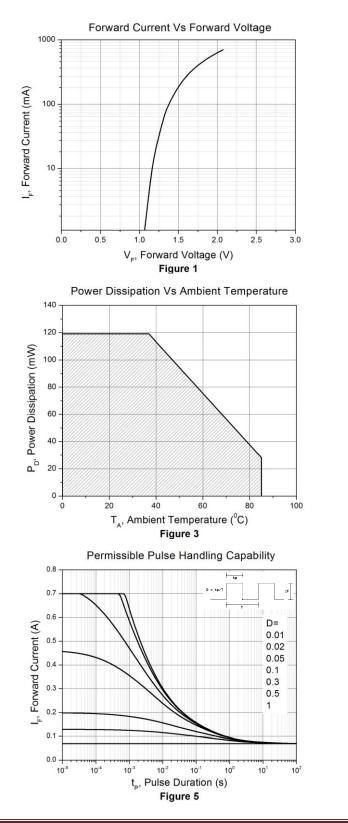
- 1. IFP Conditions--Pulse Width $\leq 100 \mu s$ and Duty $\leq 1\%$.
- 2. Soldering time \leq 5 seconds.
- 3. le Bin Rank :

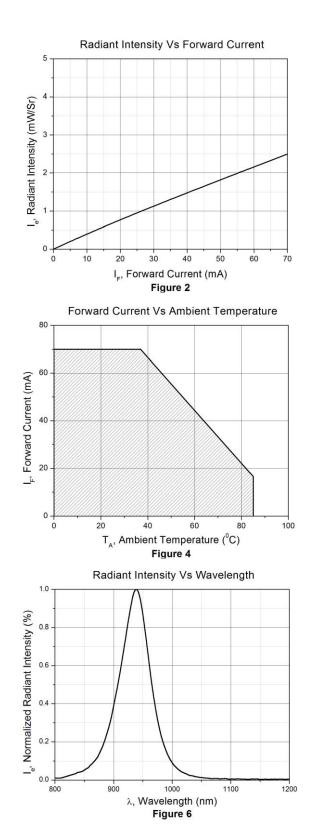
Bin Code	В	С
Min	0.4	0.65
Max	0.8	1.3



IRP1608N06-B50 SMD Type 940nm Infrared Emitter

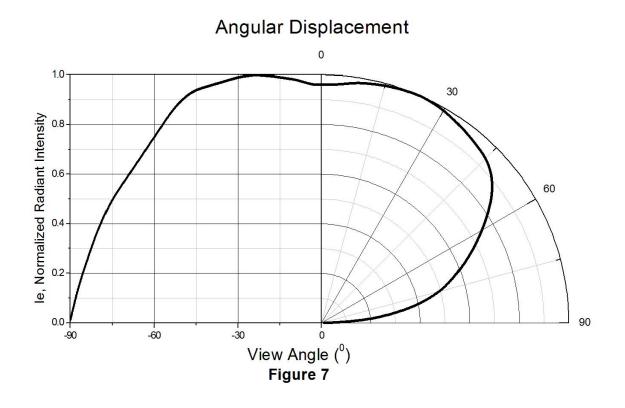
Typical Characteristic Curves





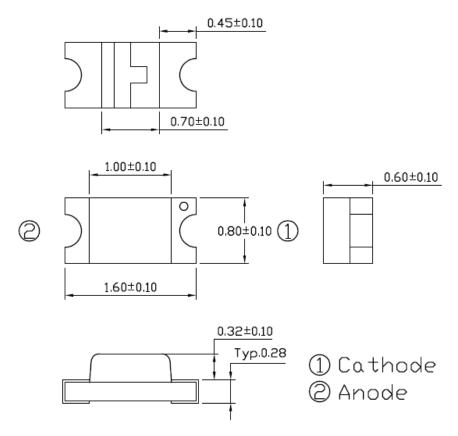


Typical Characteristic Curves

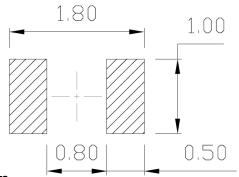




Package Dimension All dimensions are in mm, unless otherwise stated



Recommended Soldering Mask All dimensions are in mm, unless otherwise stated

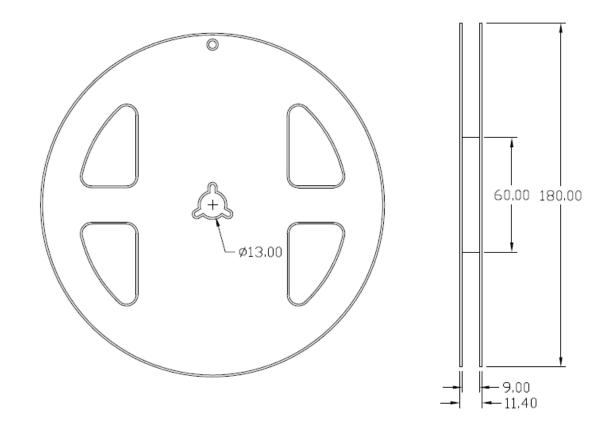


Ordering Information

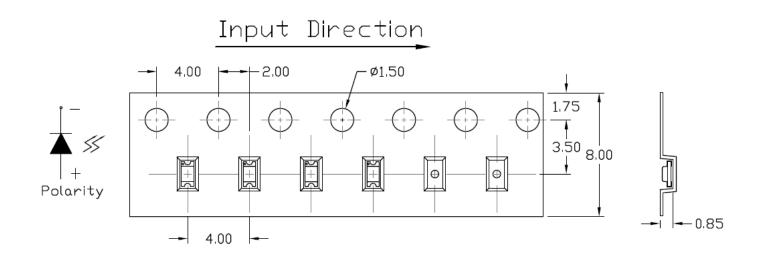
Part Number	Description	Quantity
IRP1608N06-B50	Tape & Reel	4000 pcs



Reel Dimension All dimensions are in mm, unless otherwise stated



Tape Dimension All dimensions are in mm, unless otherwise stated

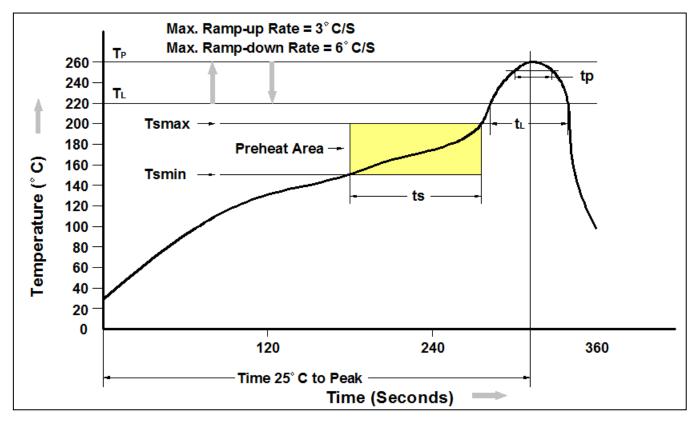




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Reflow Profile



Profile Feature	Pb-Free Assembly Profile
Temperature Min. (Tsmin)	150°C
Temperature Max. (Tsmax)	200°C
Time (ts) from (Tsmin to Tsmax)	60-120 seconds
Ramp-up Rate (t∟ to t _P)	3°C/second max.
Liquidous Temperature (TL)	217°C
Time (t _L) Maintained Above (T _L)	60 – 150 seconds
Peak Body Package Temperature	260°C +0°C / -5°C
Time (t _P) within 5°C of 260°C	30 seconds
Ramp-down Rate $(T_P \text{ to } T_L)$	6°C/second max
Time 25°C to Peak Temperature	8 minutes max.



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